Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.375 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.170 inches

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

12000.0 repetitive peak reverse voltage and 37.5 forward voltage, dc

Current Rating Per Characteristic:

3.00 milliamperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

120.0 degrees celsius junction

Special Features:

300 nanosecond maximum reverse recovery time

Test Data Document:

58260-13084424 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

72737-13084424 manufacturers specification control

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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